

TOSHIBA Intelligent Power Device High Voltage Monolithic Silicon Power IC

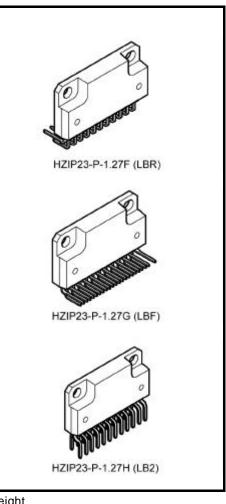
TPD4104AK

The TPD4104AK is a DC brush less motor driver using high voltage PWM control. It is fabricated by high voltage SOI process. It contains level shift high-side driver, low-side driver, IGBT outputs, FRDs and protective functions for under voltage protection circuits and thermal shutdown circuit. It is easy to control a DC brush less motor by just putting logic inputs from a MPU or motor controller to the TPD4104AK.

Features

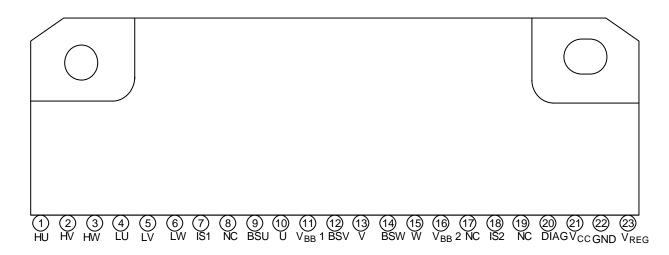
- Bootstrap circuit gives simple high side power supply.
- Bootstrap diodes are built in.
- A dead time can be set as a minimum of 1.4 $\mu s,$ and it is the best for a Sine-wave from drive.
- 3-phase bridge output using IGBTs.
- FRDs are built in.
- Included under voltage protection and thermal shutdown.
- The regulator of 7V (typ.) is built in.
- Package: 23-pin HZIP.

This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge.

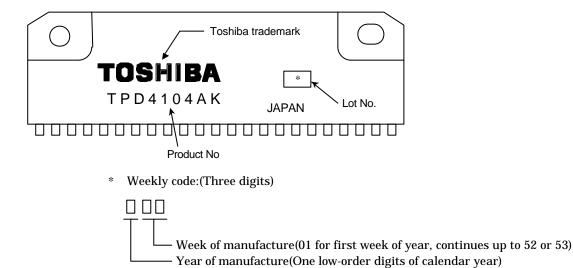


Weight HZIP23-P-1.27F : 6.1 g (typ.) HZIP23-P-1.27G : 6.1 g (typ.) HZIP23-P-1.27H : 6.1 g (typ.)

Pin Assignment

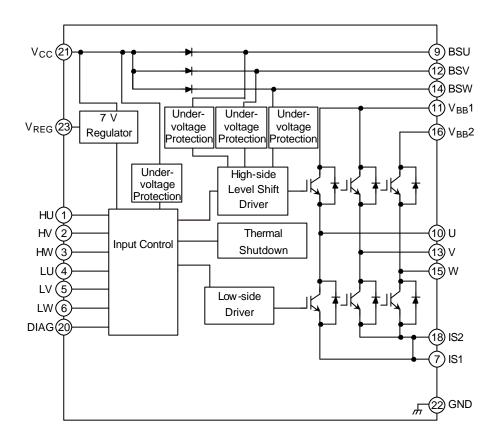


Marking





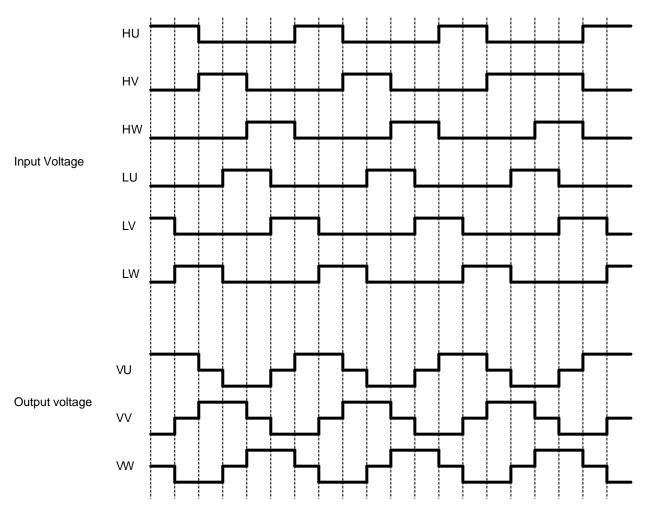
Block Diagram



Pin Description

Pin No.	Symbol	Pin Description
1	HU	The control terminal of IGBT by the side of U top arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
2	HV	The control terminal of IGBT by the side of V top arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
3	HW	The control terminal of IGBT by the side of W top arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
4	LU	The control terminal of IGBT by the side of U bottom arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
5	LV	The control terminal of IGBT by the side of V bottom arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
6	LW	The control terminal of IGBT by the side of W bottom arm. It turns off more than by 1.5V. It turns on more than by 3.5V.
7	IS1	IGBT emitter and FRD anode pin.
8	NC	Unused pin, which is not connected to the chip internally.
9	BSU	U-phase bootstrap capacitor connecting pin.
10	U	U-phase output pin.
11	V _{BB1}	U and V-phase high-voltage power supply input pin.
12	BSV	V-phase bootstrap capacitor connecting pin.
13	V	V-phase output pin.
14	BSW	W-phase bootstrap capacitor connecting pin.
15	W	W-phase output pin.
16	V _{BB2}	W-phase high-voltage power supply input pin.
17	NC	Unused pin, which is not connected to the chip internally.
18	IS2	IGBT emitter and FRD anode pin.
19	NC	Unused pin, which is not connected to the chip internally.
20	DIAG	With the diagnostic output terminal of open drain , a pull-up is carried out by resistance. It turns it on at the time of unusual.
21	V _{CC}	Control power supply pin.(15V typ.)
22	GND	Ground pin.
23	V _{REG}	7V regulator output pin.

Timing Chart



Truth Table

Mode	Input			Top arm		Bottom arm							
	нυ	нν	нw	LU	LV	LW	U	V	W	U	V	W	DIAG
	пυ	ΠV		LU	LV		phase	phase	phase	phase	phase	phase	
Normal	н	L	L	L	H	L	ΟN	OFF	OFF	OFF	ΟN	OFF	OFF
	Н	L	L	L	L	Н	ΟN	OFF	OFF	OFF	OFF	ΟN	OFF
	L	Н	L	L	L	Н	OFF	ΟN	OFF	OFF	OFF	ΟN	OFF
	L	H	L	Н	L	L	OFF	ΟN	OFF	ΟN	OFF	OFF	OFF
	L	L	Н	Н	L	L	OFF	OFF	ΟN	ΟN	OFF	OFF	OFF
	L	L	Н	L	H	L	OFF	OFF	ΟN	OFF	ΟN	OFF	OFF
Thermal shutdowr	Н	L	L	L	H	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	H	L	L	L	L	Н	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	Н	L	L	L	Н	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	Н	L	Н	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	L	Н	Н	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	L	Н	L	Н	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
Under voltage	Н	L	L	L	Н	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	Н	L	L	L	L	Н	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	Н	L	L	L	Н	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	Н	L	Н	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	L	Н	Н	L	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN
	L	L	Н	L	н	L	OFF	OFF	OFF	OFF	OFF	OFF	ΟN

Notes: Release of Thermal shutdown protection and under voltage protection depends release of a self-reset .

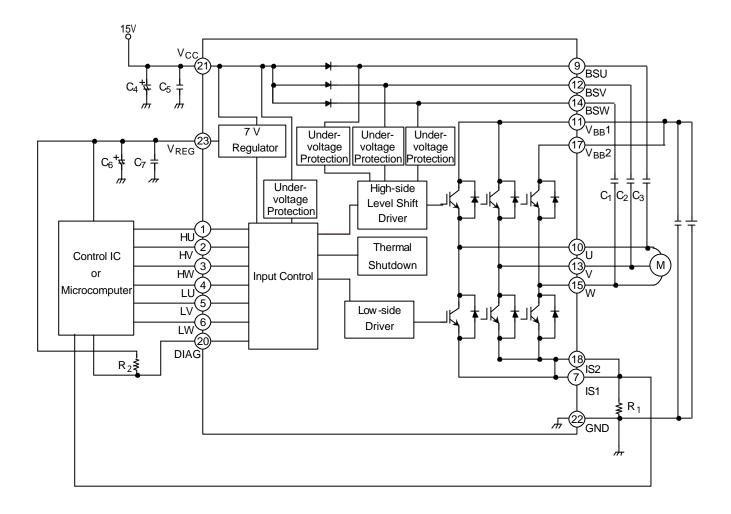
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{BB}	500	V	
i owei suppiy voltage	V _{CC}	18	V	
Output current (DC)	l _{out}	2	А	
Output current (pulse)	l _{out}	3	А	
Input voltage	V _{IN}	-0.5~7	V	
V _{REG} current	I _{REG}	50	mA	
Power dissipation (Ta = 25°C)	PC	4	W	
Power dissipation (Tc = 25°C)	PC	20	W	
Operating temperature	T _{jopr}	-20~135	°C	
Junction temperature	Тj	150	°C	
Storage temperature	T _{stg}	-55~150	°C	
Lead-heat sink isolation voltage	Vhs	1000 (1 min)	Vrms	

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit			
Operating power supply veltage	V _{BB}	—	50	280	400	V			
Operating power supply voltage	V _{CC}		13.5	15	16.5	v			
	I _{BB}	$V_{BB} = 400 V$	_	0	0.5	m 4			
Current discipation	I_{CC} $V_{CC} = 15 V$			1	5	mA			
Current dissipation	$I_{BS (ON)}$ $V_{BS} = 15 V$, high side ON		_	300	410				
	IBS (OFF)	$V_{BS} = 15 \text{ V}$, high side OFF	270	370	μA				
Input voltage	V _{IH}	V _{IN} = "H"	3.5	_	_	V			
Input voltage	V _{IL}	V _{IN} = "L"	_	_	1.5	V			
Input ourropt	μн	$V_{IN} = 5 V$			150	μΑ			
Input current	կլ	$V_{IN} = 0 V$			100				
Output saturation voltage	V _{CEsat} H	$V_{CC} = 15 V, IC = 1 A$		2.4	3	V			
Output saturation voltage	V _{CEsat} L	$V_{CC} = 15 V, IC = 1 A$		2.4	3				
	V _F H	IF = 1 A, high side		1.6	2.0	- V			
FRD forward voltage	V _F L	IF = 1 A, low side		1.6	2.0				
Regulator voltage	V _{REG}	$V_{CC} = 15 V, I_{O} = 30 \text{ mA}$	6.5	7	7.5	V			
BSD forward voltage	V _F (BSD)	$IF = 500 \ \mu A$		0.9	1.2	V			
Thermal shutdown temperature	TSD	$V_{CC} = 15 V$	135	150	180				
Thermal shutdown hysteresis	ΔTSD	$V_{CC} = 15 V$	_	50	_				
V_{CC} under voltage protection	V _{CC} UVD	—	10	11	12	V			
V_{CC} under voltage protection recovery	V _{CC} UVR	—	10.5	11.5	12.5	V			
V _{BS} under voltage protection	V _{BS} UVD	—	8	9	9.5	V			
V_{BS} under voltage protection recovery	V _{BS} UVR	—	8.5	9.5	10.5	V			
DIAG saturation voltage	V _{DIAGsat}	I _{DIAG} =5mA		_	0.5	V			
Output on delay time	t _{on}	$V_{BB} = 280 \text{ V}, \text{ IC} = 1 \text{ A}$		1.5	3	μs			
Output off delay time	t _{off}	$V_{BB} = 280 \text{ V}, \text{ IC} = 1 \text{ A}$		1.2	3	μs			
Dead time	tdead	$V_{BB} = 280 \text{ V}, \text{ IC} = 1 \text{ A}$	1.4	_		μs			
FRD reverse recovery time	t _{rr}	$V_{BB} = 280 \text{ V}, \text{ IC} = 1 \text{ A}$	_	200	_	ns			

Application Circuit Example



External Parts

Standard external parts are shown in the following table.

Part	Recommended Value	Purpose	Remarks	
C ₁ , C ₂ , C ₃	25 V/2.2 μF	Bootstrap capacitor	(Note 1)	
R ₁	0.62 Ω \pm 1% (1 W)	Current detection	(Note 2)	
C ₄	25 V/10 μF	V_{CC} power supply stability	(Note 3)	
C ₅	25 V/0.1 μF	V_{CC} for surge absorber	(Note 3)	
C ₆	16 V/1 μF	V _{REG} power supply stability	(Note 3)	
C ₇	16 V/1000 pF	V _{REG} for surge absorber	(Note 3)	
R ₃	5.1 kΩ	DIAG pin pull-up resistor	(Note 4)	

Note 1: The required bootstrap capacitance value varies according to the motor drive conditions. The capacitor is biased by V_{CC} and must be sufficiently derated for it.

- Note 2: The following formula shows the detection current: $I_O = V_R \div RIS$ (For $V_R = 0.5 V$) Do not exceed a detection current of 2 A when using this product. (Please go from the outside in the over current protection.)
- Note 3: When using this product, some adjustment is required in accordance with the use environment. When mounting, place as close to the base of this product leads as possible to improve the ripple and noise elimination.
- Note 4: The DIAG pin is open drain. Note that when the DIAG pin is connected to a power supply with a voltage higher than or equal to the V_{CC}, a protection circuit is triggered so that the current flows continuously. If not using the DIAG pin, connect to the GND.

Handling precautions

 $Please \ control \ the \ input \ signal \ in \ the \ state \ to \ which \ the \ V_{CC} \ voltage \ is \ steady. \ Both \ of \ the \ order \ of \ the \ VBB \ power \ supply \ and \ the \ V_{CC} \ power \ supply \ are \ not \ cared \ about \ either.$

Note that if the power supply is switched off as described above, this product may be destroyed if the current regeneration route to the VBB power supply is blocked when the VBB line is disconnected by a relay or similar while the motor is still running.

The excess voltage such as the voltage serge which exceed the maximum rating is added, for example, may destroy the circuit. Accordingly, be careful of handling this product or of surge voltage in its application environment.

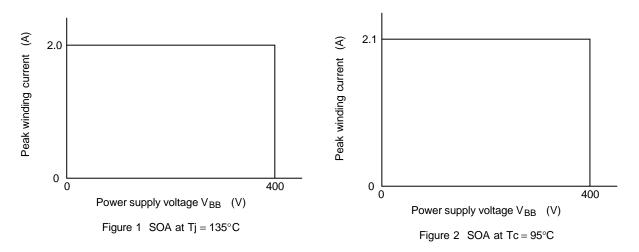
Description of Protection Function

- Under voltage protection
 This product incorporates the under voltage protection circuit to prevent the IGBT from operating in
 unsaturated mode when the V_{CC} voltage or the V_{BS} voltage drops.
 When the V_{CC} power supply falls to this product internal setting (V_{CCUVD} = 11 V typ.), all IGBT
 outputs shut down regardless of the input. This protection function has hysteresis. When the
 V_{CCUVR} (= 11.5 V typ.) reaches 0.5 V higher than the shutdown voltage, this product is
 automatically restored and the IGBT is turned on again by the input.
 When the V_{BSUVR} (= 9.5 V typ.) reaches 0.5 V higher than the shutdown voltage, the IGBT output shuts down.
 When the V_{BSUVR} (= 9.5 V typ.) reaches 0.5 V higher than the shutdown voltage, the IGBT is
 turned on again by the input signal.
- (2) Thermal shutdown

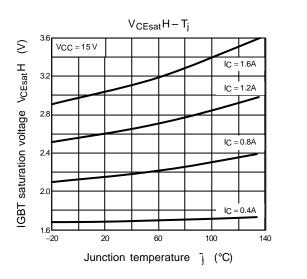
This product incorporates the thermal shutdown circuit to protect itself against the abnormal state when its temperature rises excessively.

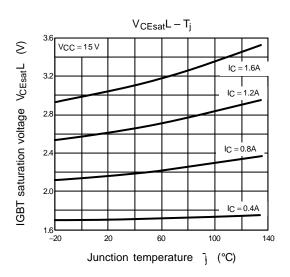
When the temperature of this chip rises due to external causes or internal heat generation and the internal setting TSD reaches 150°C, all IGBT outputs shut down regardless of the input. This protection function has hysteresis (Δ TSD = 50°C typ.). When the chip temperature falls to TSD – Δ TSD, the chip is automatically restored and the IGBT is turned on again by the input. Because the chip contains just one temperature detection location, when the chip heats up due to the IGBT, for example, the differences in distance from the detection location in the IGBT (the source of the heat) cause differences in the time taken for shutdown to occur. Therefore, the temperature of the chip may rise higher than the thermal shutdown temperature when the circuit started to operate.

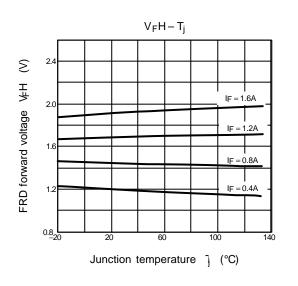
Safe Operating Area

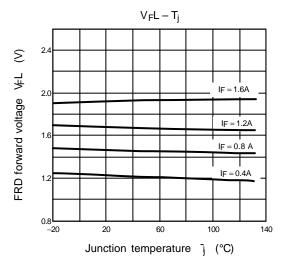


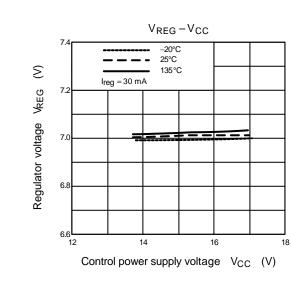
Note 1: The above safe operating areas are Tj = 135 °C (Figure 1) and Tc = 95 °C (Figure 2). If the temperature exceeds these, the safe operation areas reduce.

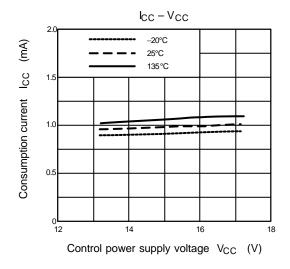


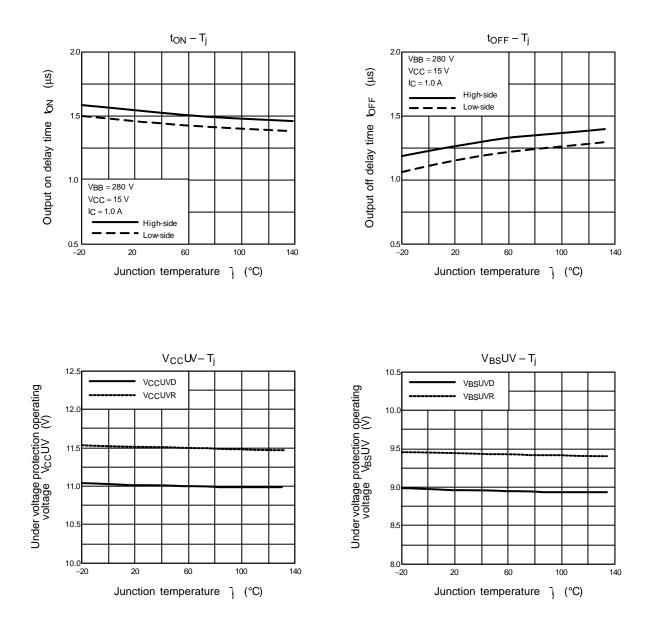


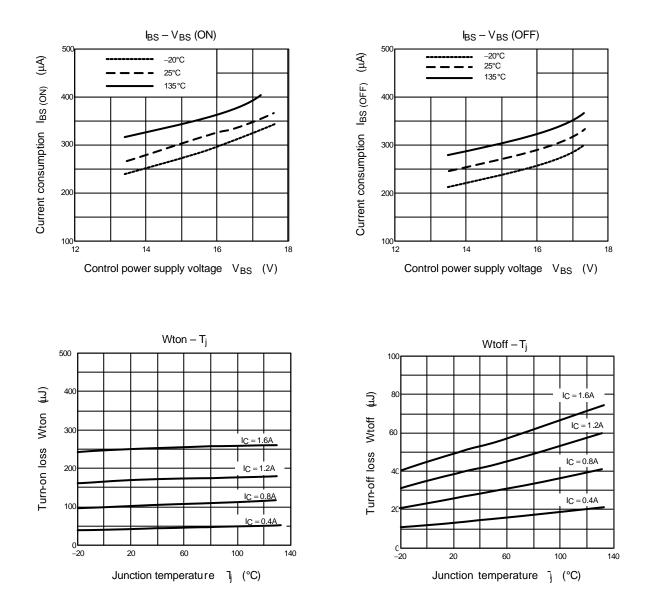






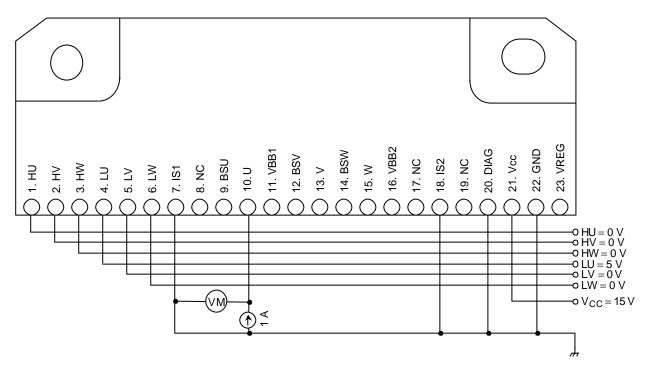




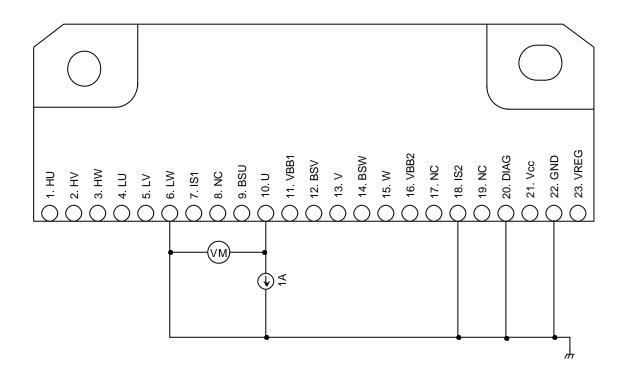


Test Circuits

IGBT Saturation Voltage (U-phase low side)

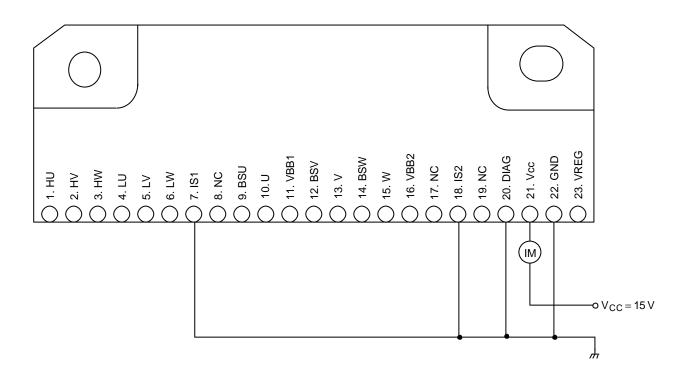




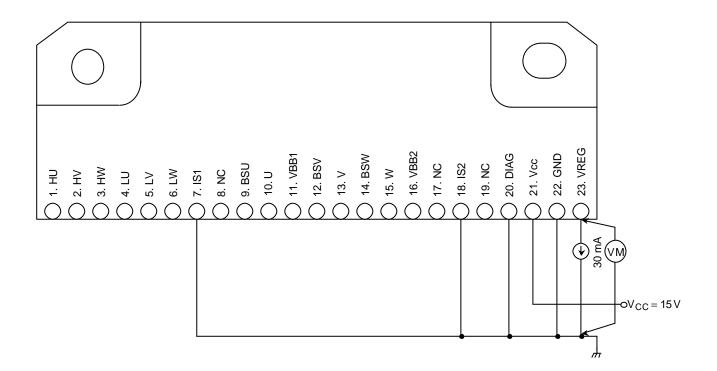




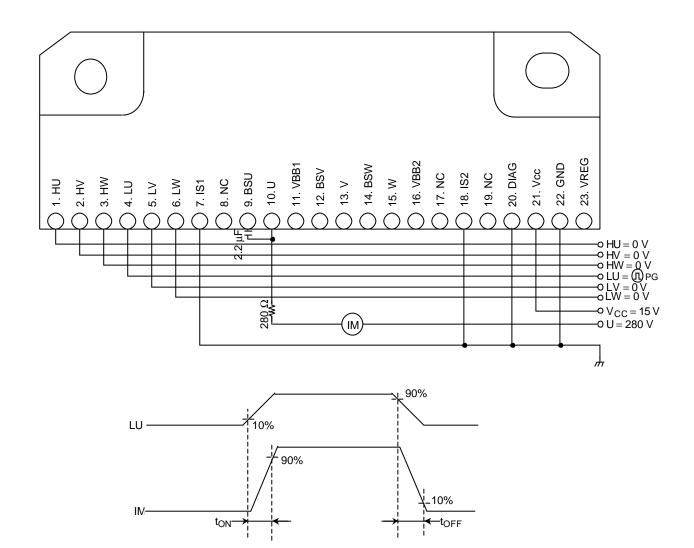
V_{CC} Current Dissipation



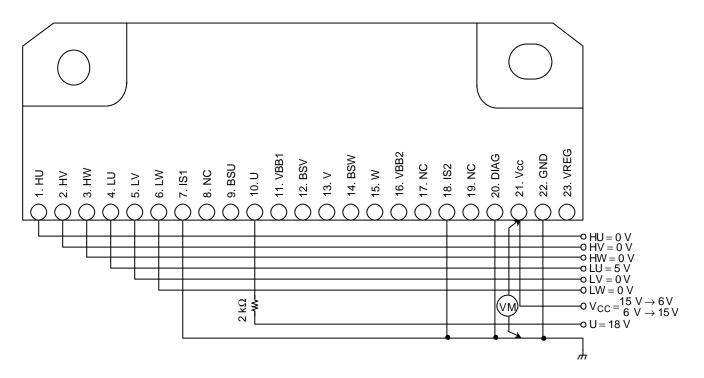
Regulator Voltage



Output ON/OFF Delay Time (U-phase low side)



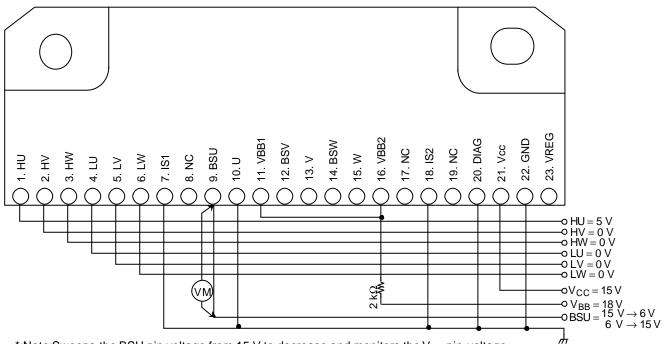
V_{CC} Under voltage Protection Operation/Recovery Voltage (U-phase low side)



*:Note:Sweeps the V_{CC} pin voltage from 15 V to decrease and monitors the U pin voltage.

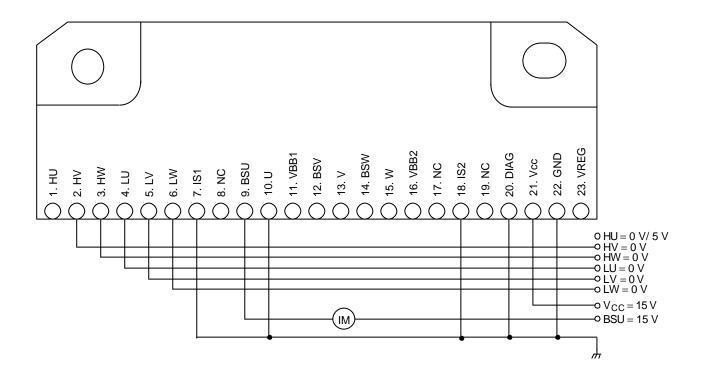
The V_{CC} pin voltage when output is off defines the under voltage protection operating voltage. Also sweeps from 6 V to increase. The V_{CC} pin voltage when output is on defines the under voltage protection recovery voltage.

V_{BS} Under voltage Protection Operation/Recovery Voltage (U-phase high side)

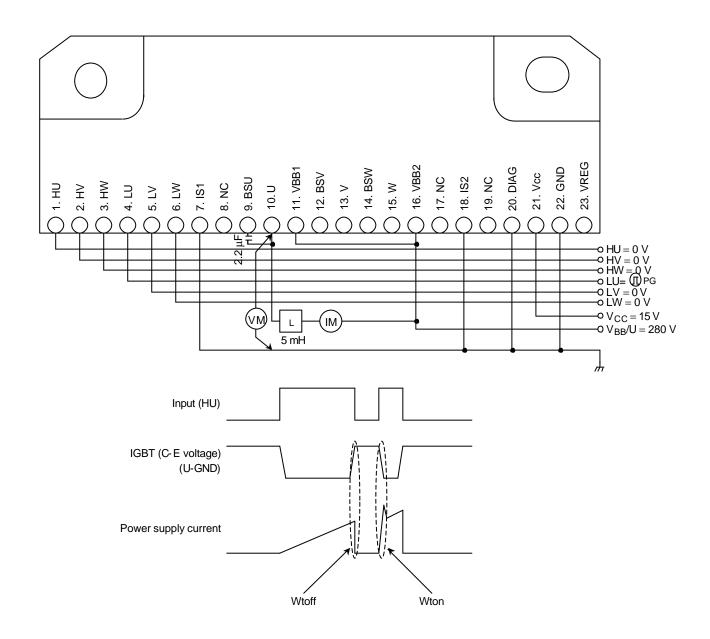


*:Note:Sweeps the BSU pin voltage from 15 V to decrease and monitors the V_{BB} pin voltage. The BSU pin voltage when output is off defines the under voltage protection operating voltage. Also sweeps the BSU pin voltage from 6 V to increase and change the HU pin voltage at $0 V \rightarrow 5 V \rightarrow 0 V$. The BSU pin voltage when output is on defines the under voltage protection recovery voltage.

V_{BS} Current Consumption (U-phase high side)



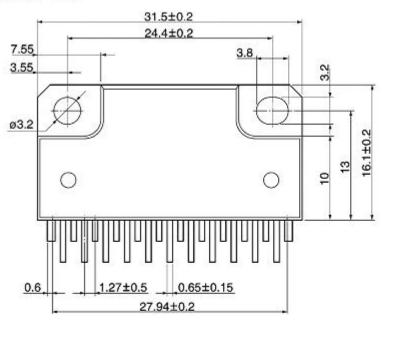
Turn-On/Off Loss (low-side IGBT + high-side FRD)

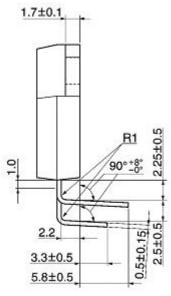


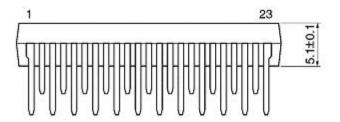
Package Dimensions

HZIP23-P-1.27F

Unit: mm





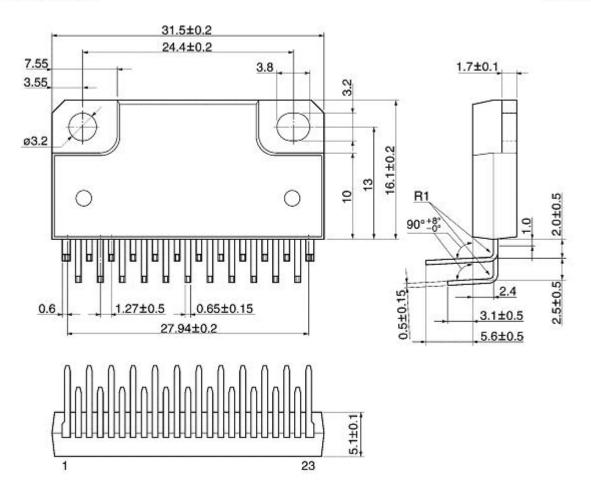


Weight: 6.1 g (typ.)

Package Dimensions

HZIP23-P-1.27G

Unit: mm

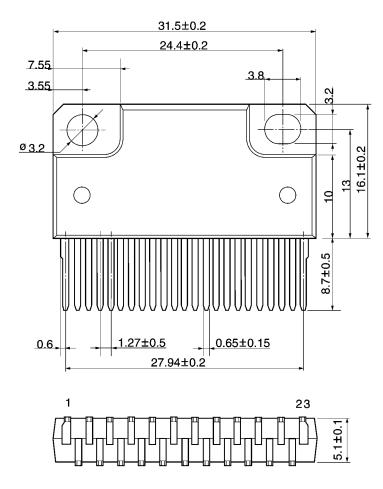


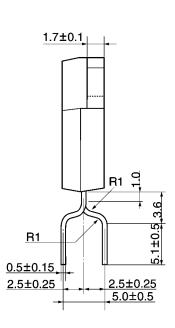
Weight: 6.1 g (typ.)

Package Dimensions

HZIP23-P-1.27H

Unit: mm





Weight: 6.1 g (typ.)

RESTRICTIONS ON PRODUCT USE

030619EBA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.